



Effect of Electro-Negativity on Beam Extraction in Negative Hydrogen Ion Sources

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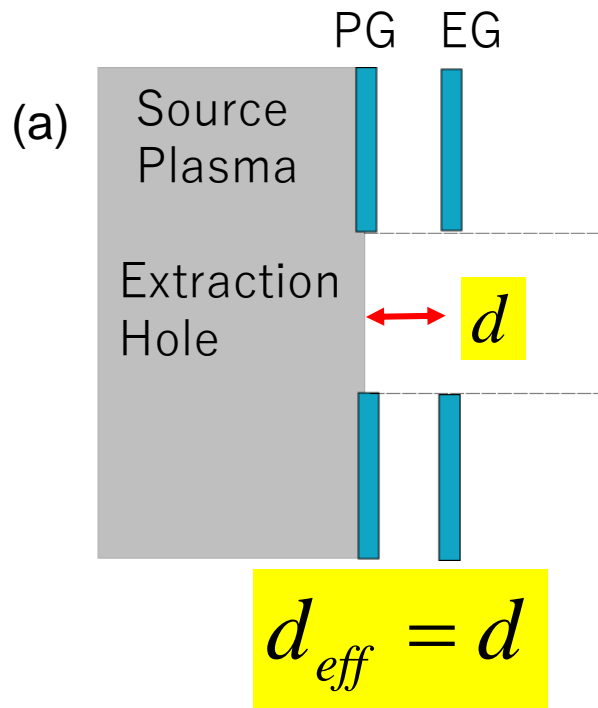


Introduction

Control of effective distance d_{eff} between the Plasma Grid (PG) and the Extraction Grid (EG)
 (or equivalently the position of the plasma meniscus)

is very important to obtain good beam quality

d : geometrical distance between the PG and the EG

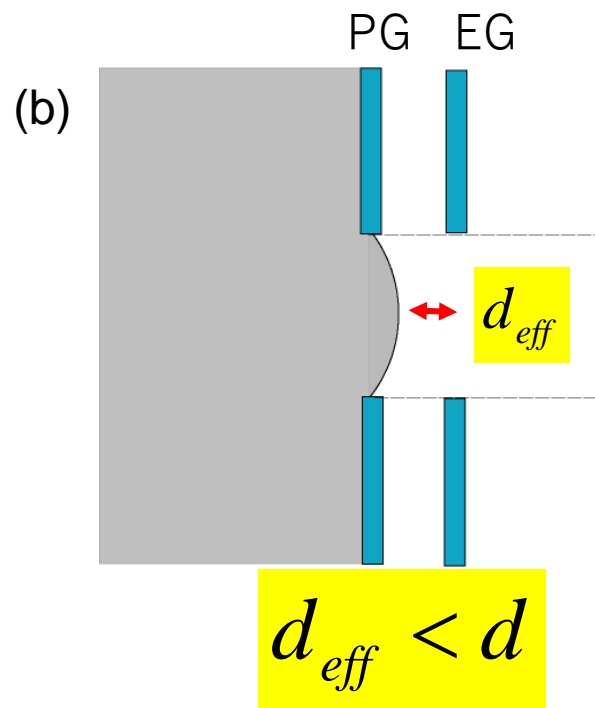


Plasma meniscus : flat

Extracted beams :

Parallel beam

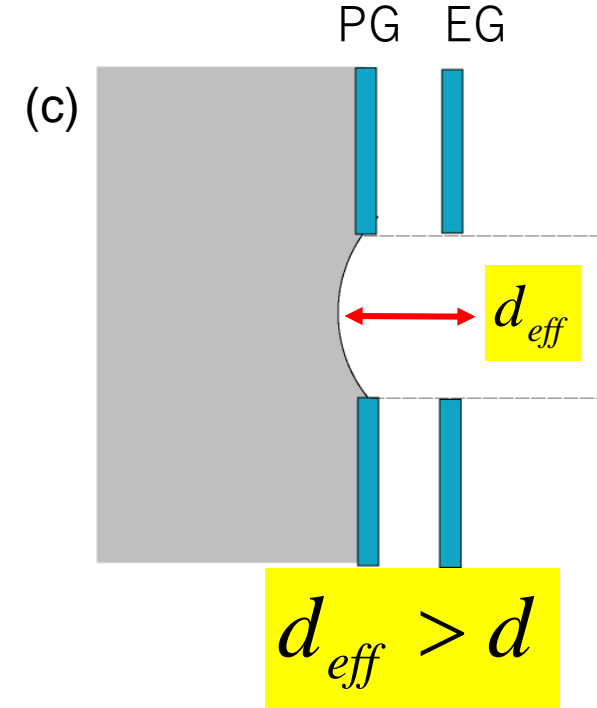
Perveance Matching



Plasma meniscus : Convex \curvearrowright

comes out towards the EG

Extracted beams : diverged



Plasma meniscus : Concave \curvearrowleft

penetrates into the source region

Extracted beams : converged but over focused





Parameter dependence of the effective distance d_{eff} between PG and EG
 (or equivalently the position of the plasma meniscus)

What are the key parameters to determine/control d_{eff} ?

How d_{eff} depends on these key parameters ?

How to control the plasma meniscus ?

For **ordinary plasmas** with **only positive ions** and **electrons**: well-known simple theory tells us:

$$(1) \quad d_{eff} = \left[\left(\frac{4\epsilon_0}{9} \right) \left(\frac{2e}{M_i} \right) \frac{V^{3/2}}{j_s} \right]^{1/2}$$

V : extraction voltage
 j_s : ion saturation current
 M_i : ion mass

ex. $d_{eff} \propto \frac{V^{3/4}}{n^{1/2}}$ (2)

However **plasmas including negative ions** :

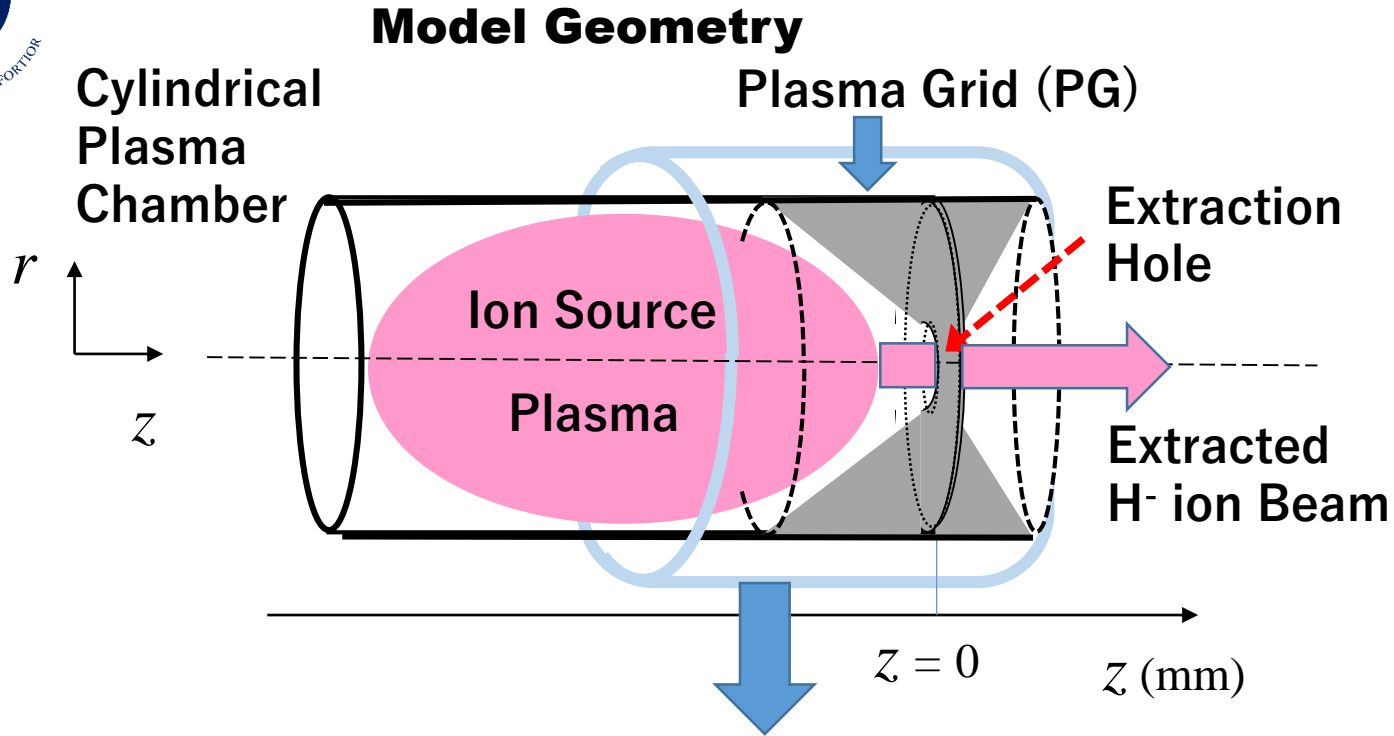
key parameters and dependence are still unclear

Final purpose of this study is **to make clear**

key parameters and

dependence of d_{eff} on these key parameters

3D PIC Model (Model Geometry and PIC Basic Eqs.)



Numerical Domain of 3D PIC simulation for a Hydrogen Negative Ion Source

3D Electrostatic PIC Basic Eqs.

Eq. of Motion

$$(3) \quad m_j \frac{dv_j}{dt} = e_j \left[\mathbf{E} + (\mathbf{v}_j \times \mathbf{B}) \right] + \text{Monte-Carlo Collision}$$

($j = \text{H}^+, \text{H}^-, \text{electron}$)

Poisson's Eq.

$$(4) \quad \nabla^2 \phi = -\frac{\rho}{\epsilon_0}$$

$$\rho = \sum_j e_j n_j$$

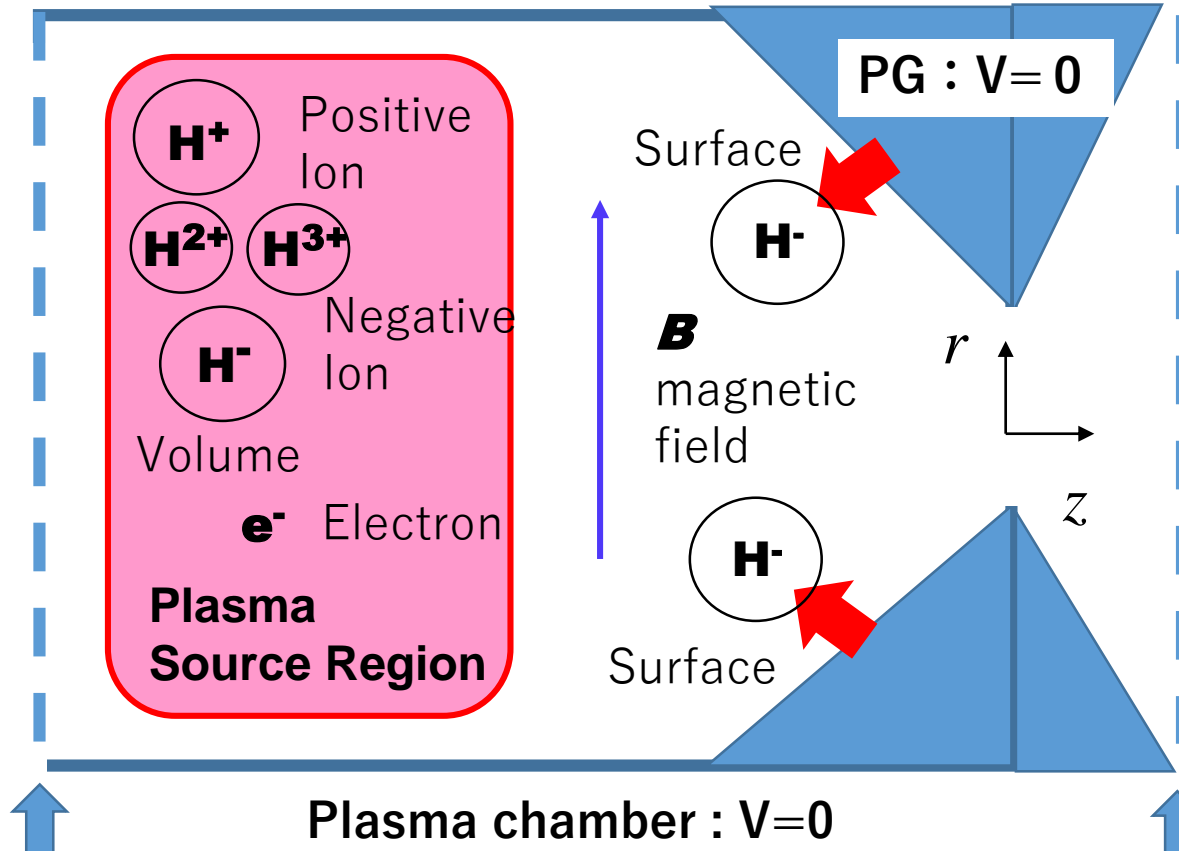
- [1] S. Nishioka, et al., J.Appl.Phys. **119**, 023302(2016).
 [2] M. Lyndqvist, et al., J.Appl.Phys. **126**, 123303(2019).





Cross Sectional View of 3D PIC Numerical Domain

Basic Input Parameters for Plasma Source Region



Parameters	Values used for PIC simulation
Plasma Density	$1.0 \times 10^{18} \text{ m}^{-3}$
Electron Temperature	3.6 eV
H ⁺ and H ⁻ Ion Temperature	1.6 eV
e ⁻ : H ⁺ : H ²⁺ : H ³⁺ : H ⁻	59.9 : 45 : 4.5 : 11.3 : 0.9

Up-stream side Boundary : V=0

EG-side Calculation Boundary : V=7 KV

- Surface production rate is changed to study effects of the H⁻ density.
- Plasma density at the sheath entrance is kept as almost the constant.

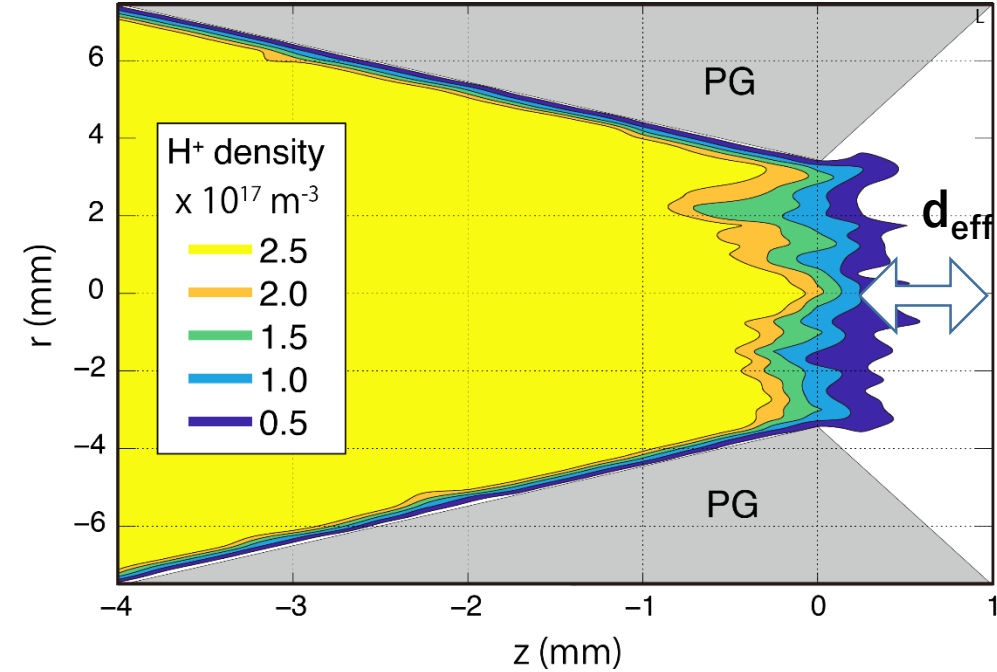
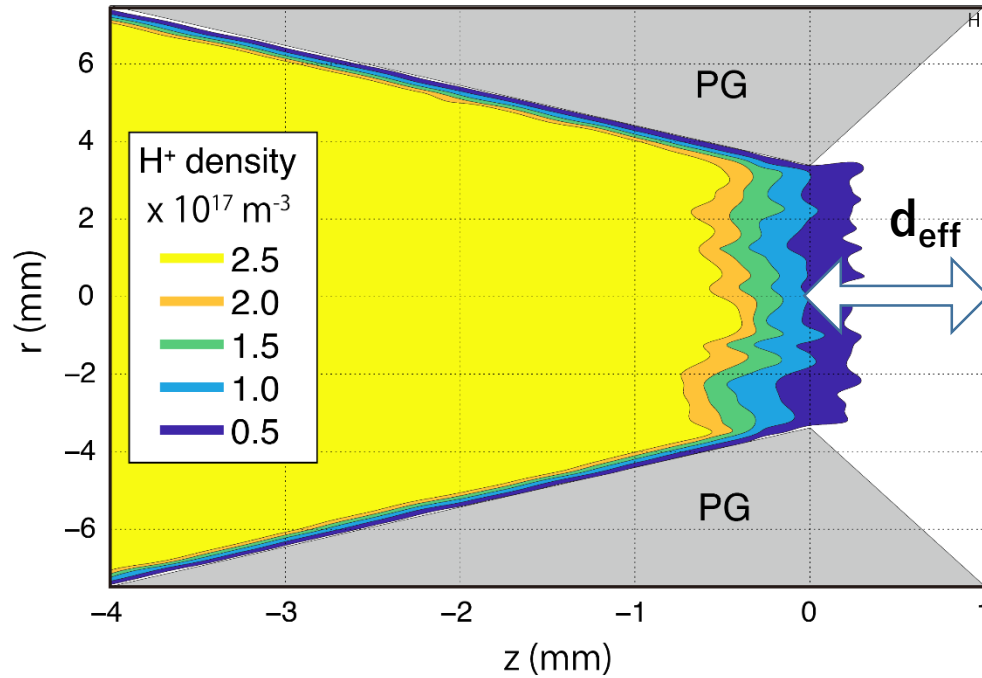


Result 1 : Comparison of n_{H^+} Density Profile and Plasma Meniscus



Case A : small surface H- production

Case B : large surface H- production



Ordinary Plasma **without H- ions** \Rightarrow effective distance $d_{eff} \propto V^{3/4} / n^{1/2}$

For both cases, the extraction voltage V and plasma density at the sheath edge n are kept the same: $V = 7\text{kV}$, $n = 0.75 \times 10^{18} \text{m}^{-3}$

However, **plasma with H- ions** \Rightarrow d_{eff} : **larger** with small surface H- production (**Case A**)
 d_{eff} : **smaller** with large surface H- production (**Case B**)

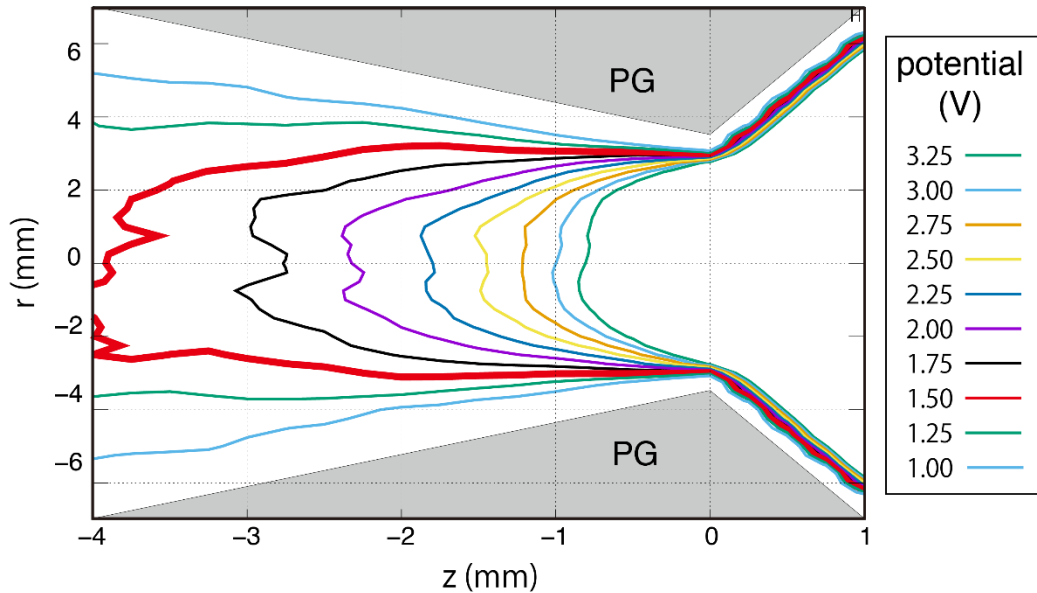


Result 2 : 2D Profile of Potential near the Extraction Hole

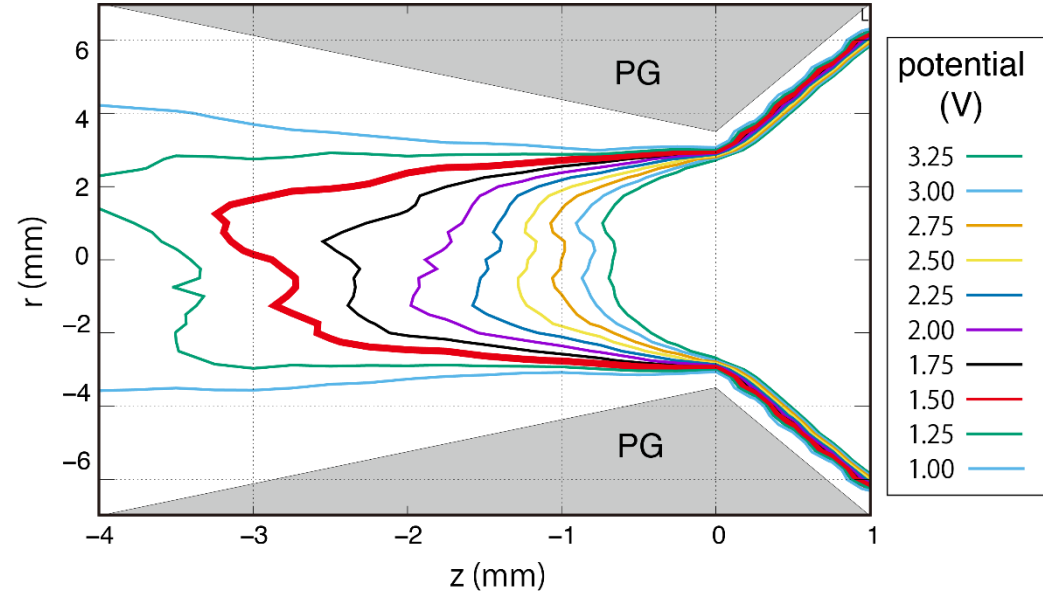


Equi-contour of Electric Potential near the Extraction Hole

Case A : small surface H⁻ production



Case B : large surface H⁻ production



Ordinary Plasma **without H⁻ ions** → effective distance $d_{eff} \propto V^{3/4} / n^{1/2}$

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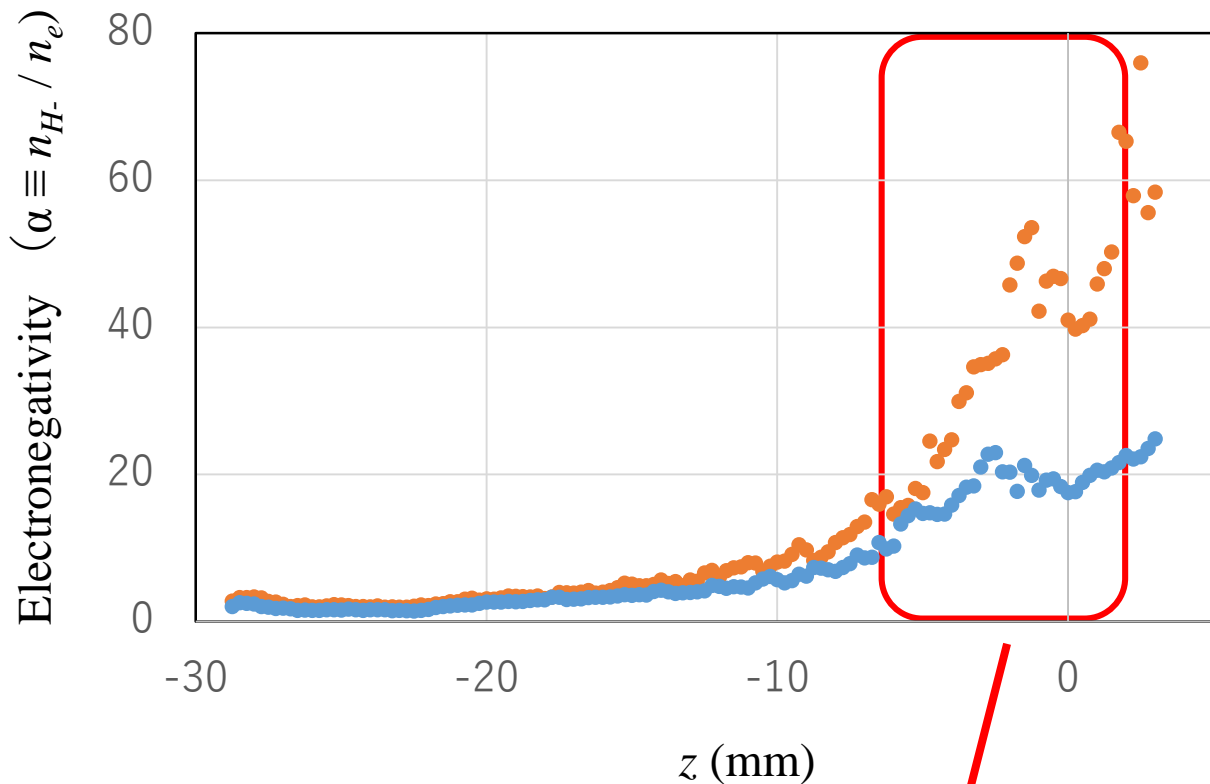
However, plasma **with H⁻ ions** → d_{eff} : **larger** with smaller surface H⁻ production (**Case A**)
 d_{eff} : **smaller** with larger surface H⁻ production (**Case B**)

Why ? What is the **key parameter for the effective distance d_{eff}** ?

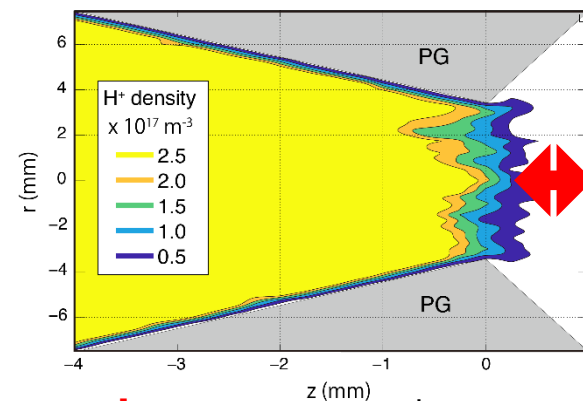
Result 3 : Spatial Profile of Electro-negativity ($\alpha \equiv n_{H^-} / n_e$)



● Case B ● Case A

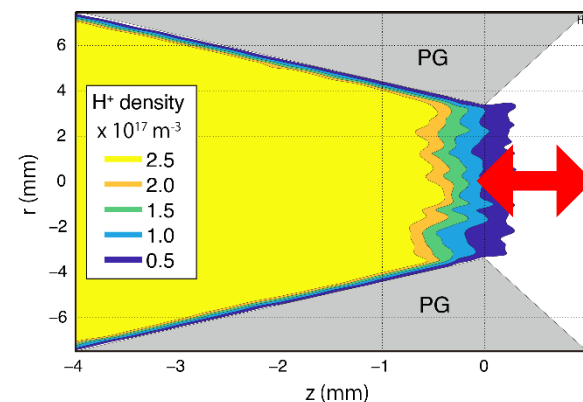


Case B : High α near the extraction hole



d_{eff} : small

Case A : Low α near the extraction hole



d_{eff} : large

Electro-negativity α : case A \rightarrow low case B \rightarrow high
 d_{eff} with surface H⁻ production is largely depends on Electro-negativity α neat the PG.



Main Plasma Parameters for 3D PIC simulation

Parameters	Values used for PIC simulation
Electron Density	$1.8 \times 10^{17} \text{ m}^{-3}$
Electron Temperature	0.8 eV
H ⁺ Ion Temperature	0.3 eV
H ⁻ Ion Temperature	a. 0.1 eV (Volume Produced H ⁻) b. 1 eV / 0.25 eV (Surface Produced H ⁻ , Initial Energy/Temperature)
H ₂ molecular density	$1.88 \times 10^{19} \text{ m}^{-3}$ (equivalently 0.3 Pa)
H ₂ molecular Temperature	0.1 eV
H atom Temperature	0.3 eV
H/H ₂ Density Ratio	0.5

Systematic 3D PIC modeling of H⁻ extraction for the NIFS R&D H⁻ source

Detailed Information
ex. **Model Geometry** of
Plasma Chamber
PG (Plasma Grid)
EG (Extraction Grid)
AG (Acceleration Grid)
➔ **Poster Presentation**

Poster #17 K.Miyamoto et al.:

“ Study of negative ion beam emittance Characteristics using PIC-MCC simulation ”

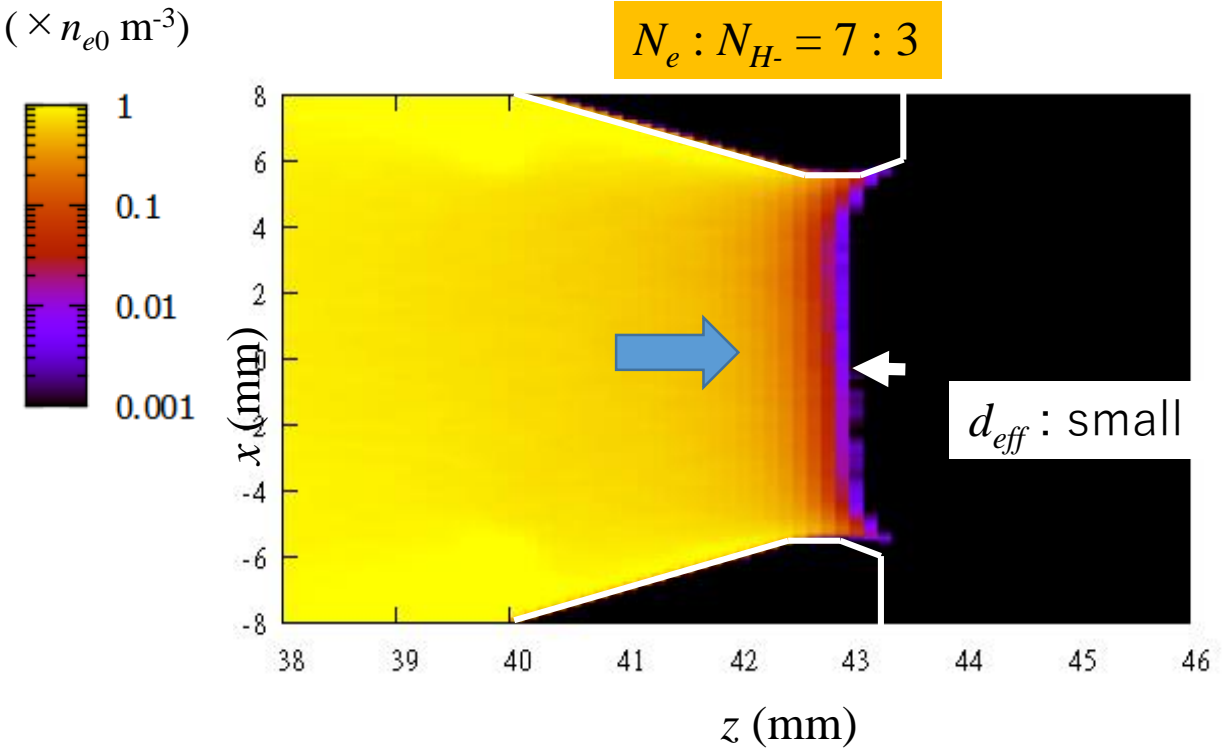
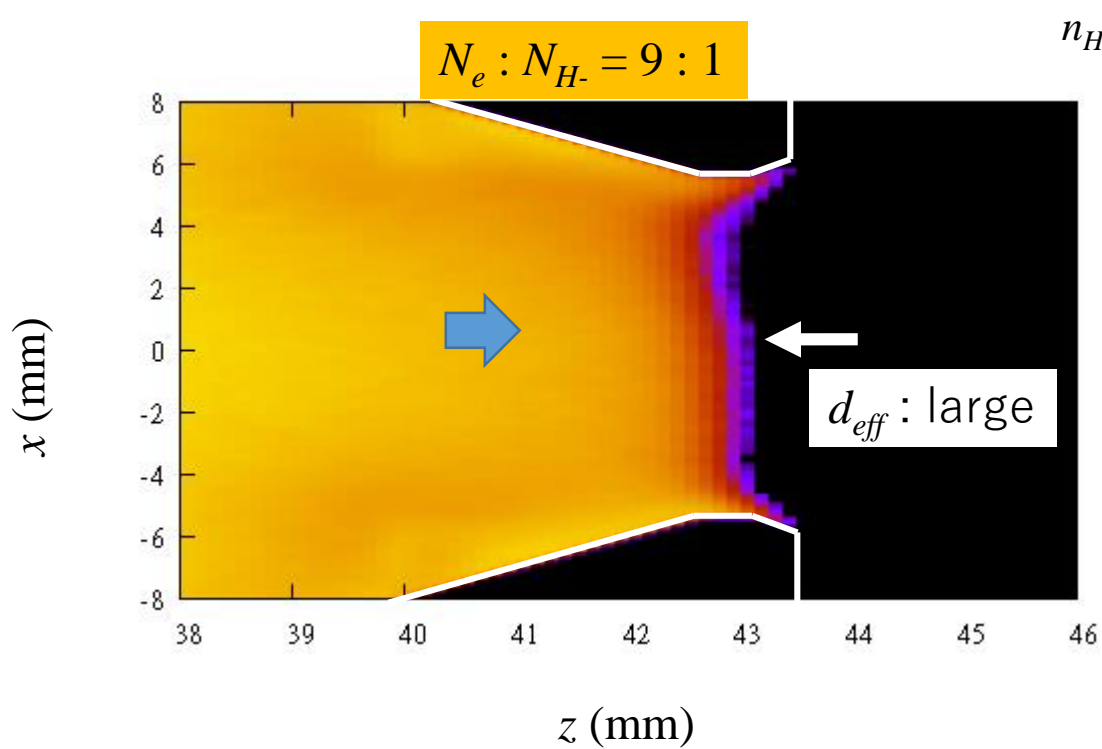




Spatial Profile of H⁺ Ion Density n_{H^+} near the Extraction Hole (with Volume and Surface H⁻ production)

Case A : Low α near the extraction hole

Case B : High α near the extraction hole



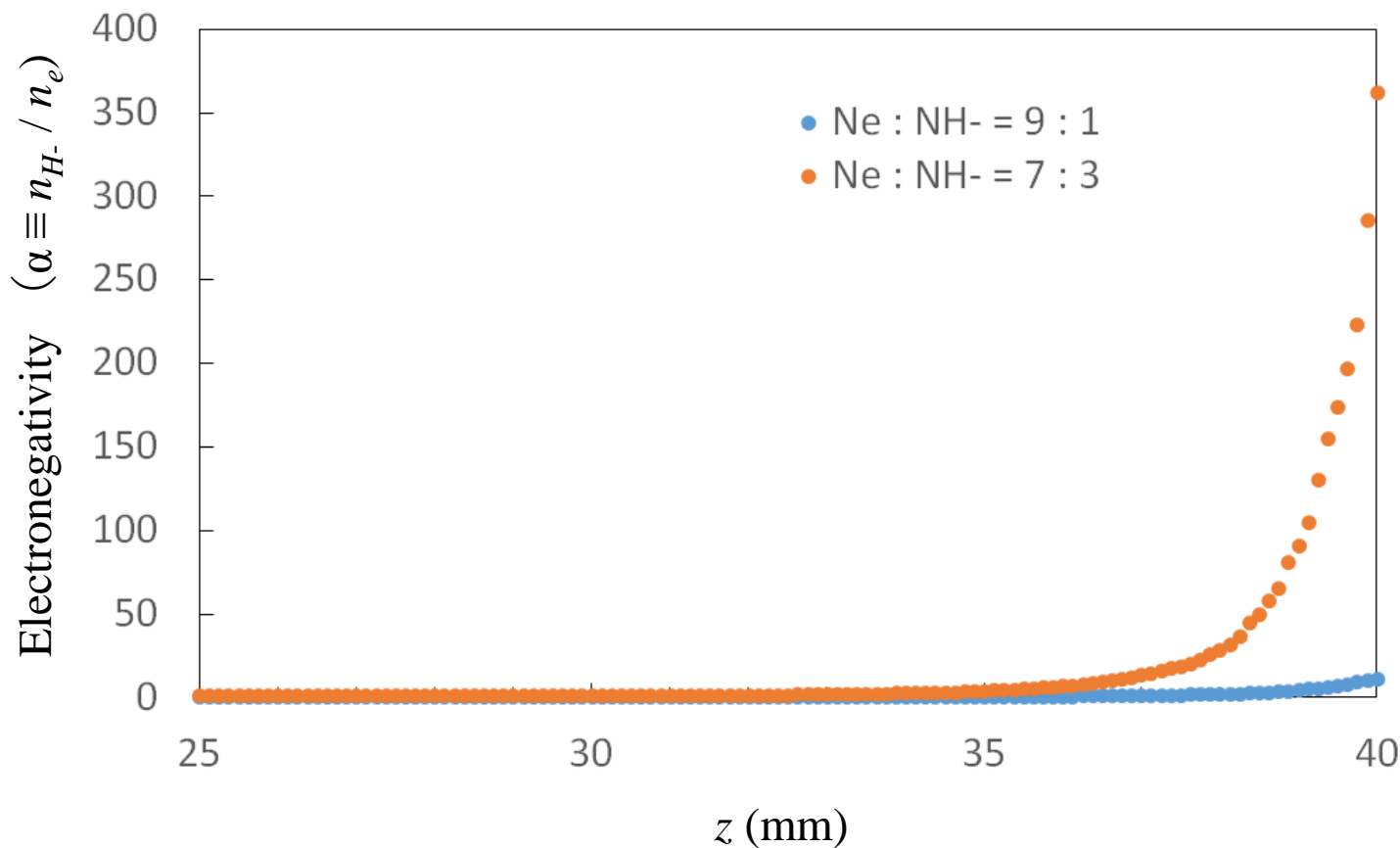
In **Case B**, i.e., in **High- α** case,
plasma meniscus is more **pushed towards outside**, i.e. **towards the EG**.

Position and shape of the **plasma meniscus** largely depends on **Electro-negativity α** neat the PC

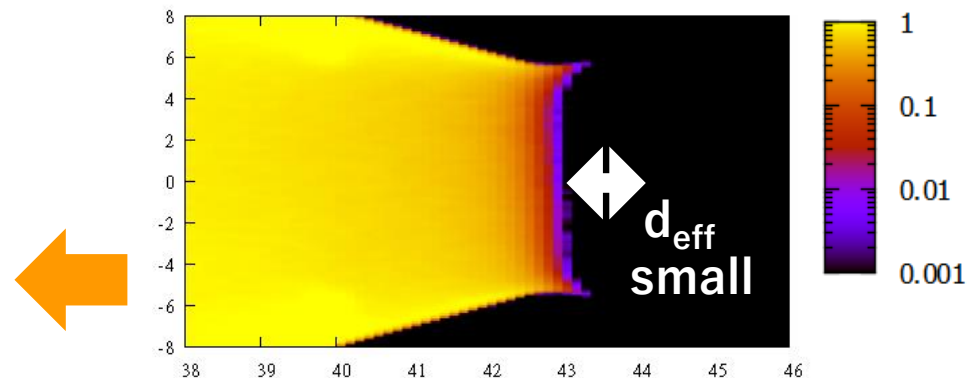




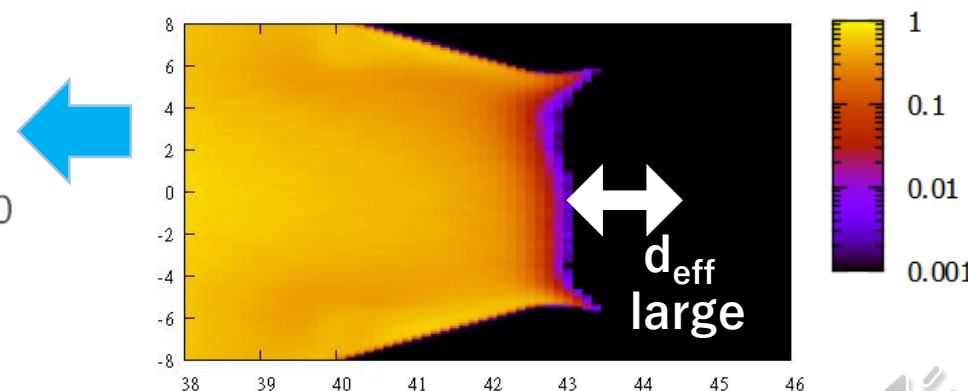
1D Spatial Profile of Electro-negativity ($\alpha \equiv n_{H^-} / n_e$) along the z -axis (with Volume and Surface H⁻ production)



Case B : High α near the extraction hole



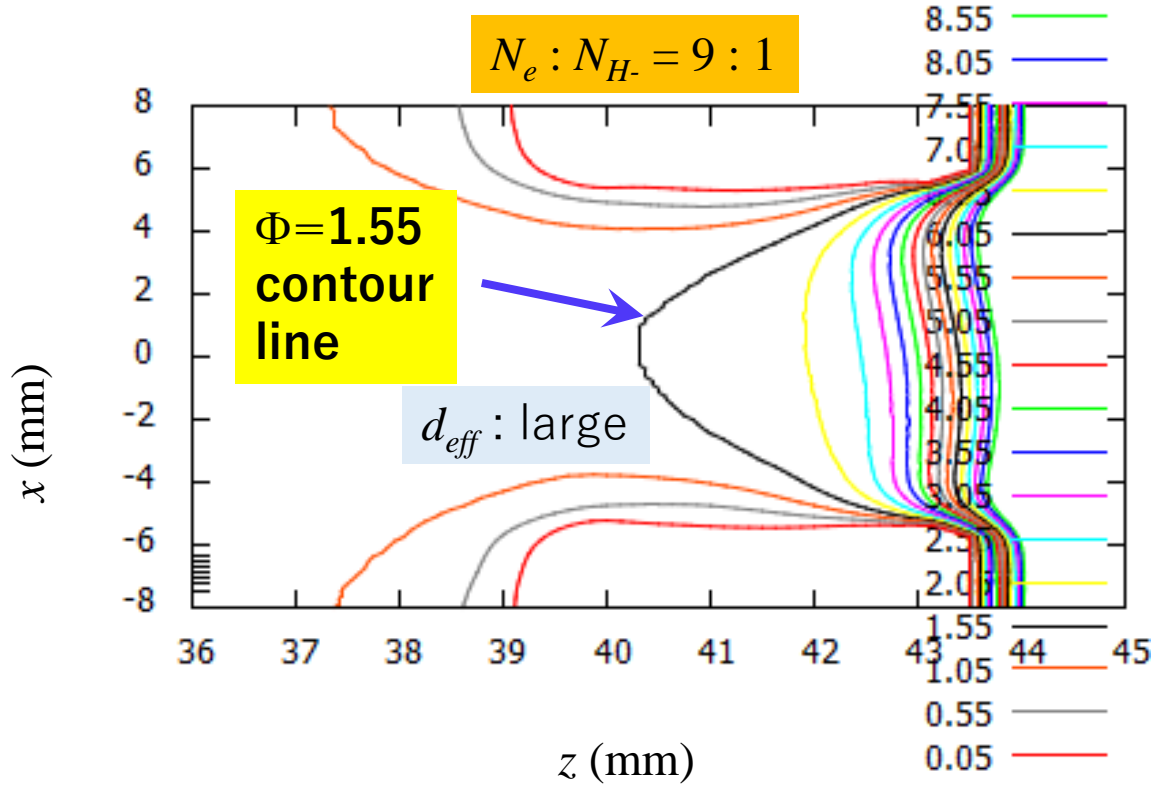
Case A : Low α near the extraction hole



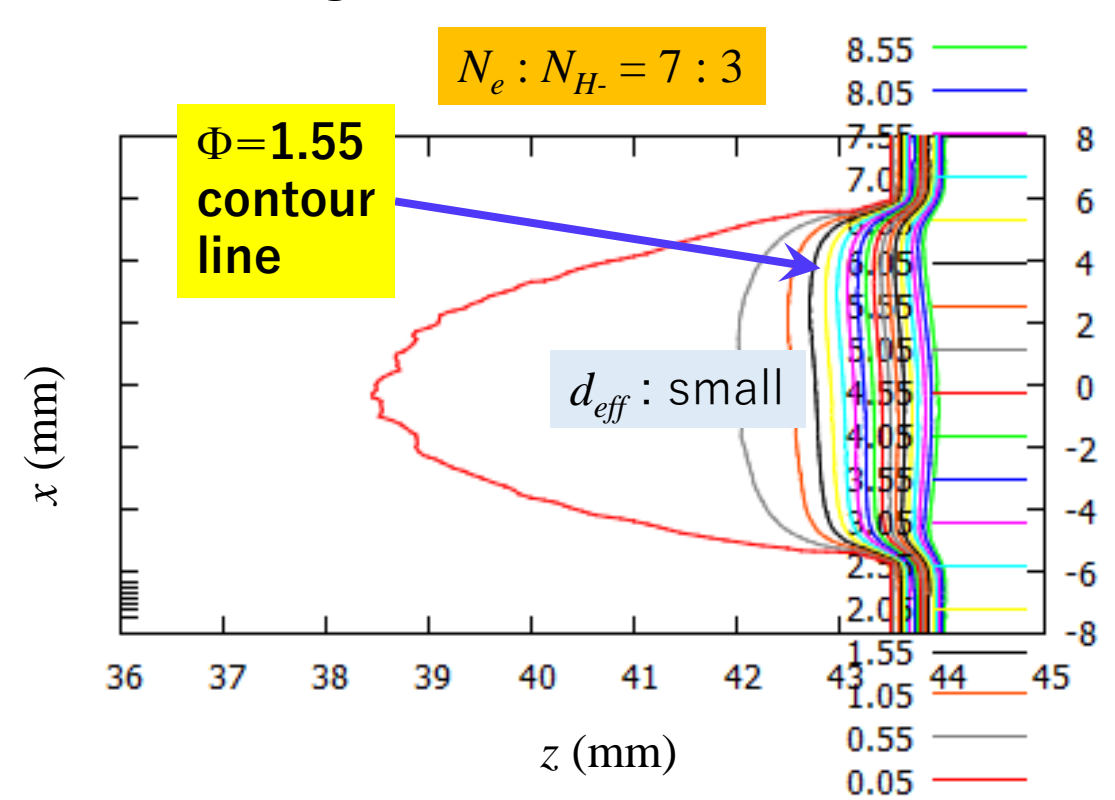


Equi-contour lines of Electric Potential near the Extraction Hole (with Volume and Surface H⁻ production)

Case A : Low α near the extraction hole



Case B : High α near the extraction hole



In **Case A**, i.e., in **Low- α** case, **EG voltage** penetrates **more deeply** into the plasma **source region**, while, in **Case B**, **EG voltage** is **well shielded**, and **not so deeply** penetrates into source region.

Electro-negativity α near the PG is a **very important parameter** to **control the plasma meniscus**.





Comparison with Simple Analytic Theory (by .K.Miyamoto)

Inside the source

=> Current through the sheath

$$J_{sat} = J_e + J_{H^-}$$

(ion saturation current)

*including effects of H⁻ ions

$$J_{sat} = J^{ext}$$



current continuity

Outside the source

(between the PG and EG)

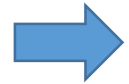
=> Total Extracted Current

$$J^{ext} = J_e^{ext} + J_{H^-}^{ext}$$

(Child-Langmuir current)



Effective distance d_{eff} between the PG and the EG ($J_{sat} = J^{ext}$)



$$d_{eff} \propto \frac{1}{n_{i0}^{1/2}} \left(\frac{M_i}{m_e} \right)^{1/4} \left(\frac{1}{1 + \alpha} \right)^{1/2} V^{3/4} \quad (3)$$

M_i : ion mass

m_e : electron mass

n_{i0} : H⁺ ion density ($n_{i0} \sim n_{e0} + n_{H^-}$)

V : extraction voltage

electro-negativity

$$\alpha \equiv \frac{n_{H^-}}{n_e}$$

$\alpha \rightarrow$ lower $d_{eff} \rightarrow$ larger

$\alpha \rightarrow$ higher $d_{eff} \rightarrow$ smaller

: plasma meniscus **penetrates deeper** into the plasma

: plasma meniscus **penetrates shallower** into the plasma

Electro-negativity α near the PG is a very important parameter to control d_{eff} (the plasma meniscus).

For the case **with surface H⁻ production**, K.Miyamoto has also derived the **expression** for d_{eff} and also **strongly depends on the electro-negativity α** .





Using 3D PIC Simulation (Keio-BFX code) and simple Analytic Theory

Effects of H⁻ density (density ratio of H⁻ ions and electrons) have been **studied on**

- **Plasma shielding distance** of the extraction voltage into the source plasma
 i.e. **Effective distance between the PG and EG : d_{eff}**
- **Plasma meniscus**
- **Ordinary H⁺- electron plasma** (plasma density : $n=n_i \sim n_e$)

$$d_{eff} \propto \frac{V^{3/4}}{n^{1/2}}$$

Plasma with surface produces H⁻ ions (H⁻ density n_{H^-} and $n=n_i \sim n_e + n_{H^-}$)

d_{eff} : largely depends on the ratio $\alpha = n_{H^-} / n_e$ around the extraction hole

$\alpha \rightarrow$ low : $d_{eff} \rightarrow$ large , while

$\alpha \rightarrow$ high : $d_{eff} \rightarrow$ small





- **The same tendency has been obtained by another 3D PIC simulation** (by Miyamoto) for the NIFS H- R&D source
- These **PIC simulation results** are also **supported by** comparison with **simple analytic theory** of the effective distance between the PG and EG (developed by K.Miyamoto)
- These **simulation and theoretical results suggests** :
 - **Control concept of the effective distance d_{eff} / meniscus shape** (in other words how to get the perveance matching)
in the plasma with H⁻ ions is shown to be largely **different from** in the **ordinary plasma without H⁻ ion**
 - **One of the key control parameters is** the electro-negativity (**density ratio n_{H^-}/n_e**) around the extraction hole

